

**PI6C20800S**

**PCI Express® 1:8 HCSL Clock Buffer**

**Features**

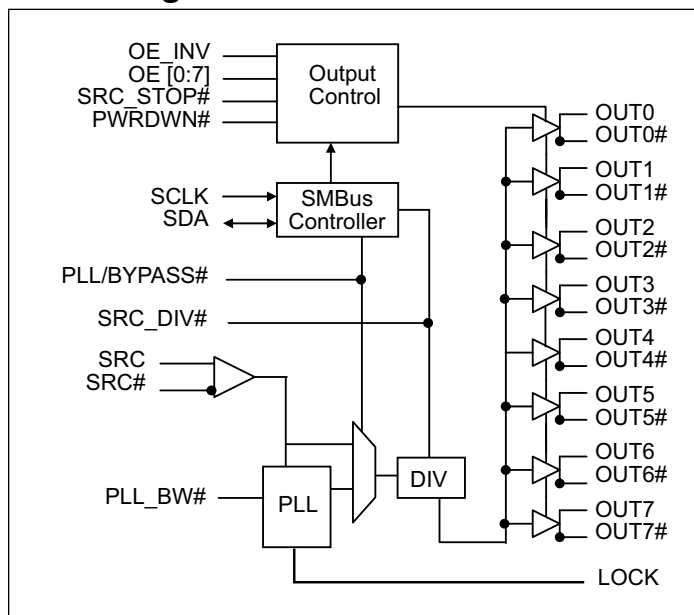
- Phase jitter filter for PCIe® application
- Eight Pairs of Differential Clocks
- Low skew < 50ps (PI6C20800S), <60ps (PI6C20800SI)
- Low Cycle-to-cycle jitter < 70ps
- Output Enable for all outputs
- Outputs Tristate control via SMBus
- Power Management Control
- Programmable PLL Bandwidth
- PLL or Fanout operation
- 3.3V Operation
- Industrial Temperature Option - PI6C20800SI
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. “Green” Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative.
- Packaging (Pb-Free & Green):
  - 48-Pin SSOP (V)
  - 48-Pin TSSOP (A)

<https://www.diodes.com/quality/product-definitions/>

**Description**

The PI6C20800S is a PCI Express®, high-speed, low-noise differential clock buffer designed to be a companion to PI6C410BS PCI Express clock generator for Intel server chipsets. The device distributes the differential SRC clock from PI6C410BS to eight differential pairs of clock outputs either with or without PLL. The input SRC clock can be divided by 2 when SRC\_DIV# is LOW. The clock outputs are controlled by input selection of SRC\_STOP#, PWRDWN# and SMBus, SCLK and SDA. When input of either SRC\_STOP# or PWRDWN# is LOW, the output clocks are Tristated. When PWRDWN# is LOW, the SDA and SCLK inputs must be Tristated.

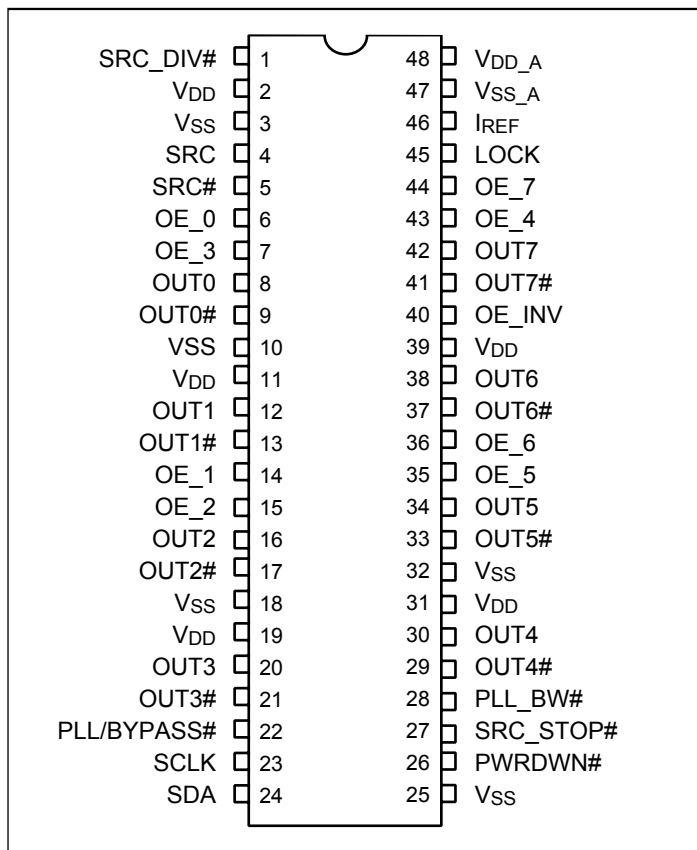
**Block Diagram**



**Notes:**

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated’s definitions of Halogen- and Antimony-free, “Green” and Lead-free.
3. Halogen- and Antimony-free “Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Configuration



## Pin Descriptions

Pin #	Pin Name	Type	Descriptions
1	SRC_DIV#	Input	3.3V LVTTTL input for selecting input frequency divide by 2, active LOW.
4, 5	SRC & SRC#	Input	0.7V Differential SRC input from PI6C410 clock synthesizer
6, 7, 14, 15, 35, 36, 43, 44	OE [0:7]	Input	3.3V LVTTTL input for enabling outputs, active HIGH.
40	OE_INV	Input	3.3V LVTTTL input for inverting the OE, SRC_STOP# and PWRDWN# pins. When 0 = same stage When 1 = OE[0:7], SRC_STOP#, PWRDWN# inverted.
8, 9, 12, 13, 16 17, 20, 21, 29, 30, 33, 34, 37, 38, 41, 42	OUT[0:7] & OUT[0:7]#	Output	0.7V Differential outputs
22	PLL/BYPASS#	Input	3.3V LVTTTL input for selecting fan-out of PLL operation.
23	SCLK	Input	SMBus compatible SCLOCK input
24	SDA	I/O	SMBus compatible SDATA
46	IREF	Input	External resistor connection to set the differential output current
27	SRC_STOP#	Input	3.3V LVTTTL input for SRC stop, active LOW

**PI6C20800S**

**Pin Descriptions Cont.**

Pin #	Pin Name	Type	Descriptions
28	PLL_BW#	Input	3.3V LVTTTL input for selecting the PLL bandwidth
26	PWRDWN#	Input	3.3V LVTTTL input for Power Down operation, active LOW
45	LOCK	Output	3.3V LVTTTL output, transition high when PLL lock is achieved (Latched output)
2, 11, 19, 31, 39	V <sub>DD</sub>	Power	3.3V Power Supply for Outputs
3, 10, 18, 25, 32	V <sub>SS</sub>	Ground	Ground for Outputs
47	V <sub>SS_A</sub>	Ground	Ground for PLL
48	V <sub>DD_A</sub>	Power	3.3V Power Supply for PLL

## Serial Data Interface (SMBus)

This part is a slave only SMBus device that supports indexed block read and indexed block write protocol using a single 7-bit address and read/write bit as shown below.

### Address Assignment

A6	A5	A4	A3	A2	A1	A0	W/R
1	1	0	1	1	1	0	0/1

### Data Write Protocol

1 bit	7 bits	1	1	8 bits	1	8 bits	1	8 bits	1	8 bits	1	1 bit
Start bit	Slave Addr	W	Ack	Register offset	Ack	Byte Count = N	Ack	Data Byte Offset	Ack	Data Byte N - 1	Ack	Stop bit

**Note:**

1. Register offset for indicating the starting register for indexed block write and indexed block read. Byte Count in write mode cannot be 0.

### Data Read Protocol

1 bit	7 bits	1	1	8 bits	1	1	7 bits	1	1	8 bits	1	8 bits	1	8 bits	1	1 bit
Start bit	Slave Addr	W	Ack	Register offset	Ack	Repeat Start	Slave Addr	R	Ack	Byte Count = N	Ack	Data Byte Offset	Ack	Data Byte N - 1	Not Ack	Stop bit

**Note:**

1. Register offset for indicating the starting register for indexed block write and indexed block read.

### Data Byte 0: Control Register

Bit	Descriptions	Type	Power Up Condition	Output(s) Affected	Pin
0	SRC_DIV# 0 = Divide by 2 1 = Normal	RW	1 = x1	OUT[0:7], OUT[0:7]#	NA
1	PLL/BYPASS# 0 = Fanout 1 = PLL	RW	1 = PLL	OUT[0:7], OUT[0:7]#	NA
2	PLL Bandwidth 0 = HIGH Bandwidth, 1 = LOW Bandwidth	RW	1 = Low	OUT[0:7], OUT[0:7]#	NA
3	RESERVED				
4	RESERVED				
5	RESERVED				
6	SRC_STOP# 0 = Driven when stopped 1 = Tristate	RW	0 = Driven when stopped	OUT[0:7], OUT[0:7]#	
7	PWRDWN# 0 = Driven when stopped 1 = Tristate	RW	0 = Driven when stopped	OUT[0:7], OUT[0:7]#	NA

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**Data Byte 1: Control Register**

Bit	Descriptions	Type	Power Up Condition	Output(s) Affected	Pin
0	<b>OUTPUTS enable</b> 1 = Enabled 0 = Disabled	RW	1 = Enabled	OUT0, OUT0#	NA
1		RW	1 = Enabled	OUT1, OUT1#	NA
2		RW	1 = Enabled	OUT2, OUT2#	NA
3		RW	1 = Enabled	OUT3, OUT3#	NA
4		RW	1 = Enabled	OUT4, OUT4#	NA
5		RW	1 = Enabled	OUT5, OUT5#	NA
6		RW	1 = Enabled	OUT6, OUT6#	NA
7		RW	1 = Enabled	OUT7, OUT7#	NA

**Data Byte 2: Control Register**

Bit	Descriptions	Type	Power Up Condition	Output(s) Affected	Pin
0	<b>Allow control of OUTPUTS with                      assertion of SRC_STOP#</b> 0 = Free running 1 = Stopped with SRC_Stop#	RW	0 = Free running	OUT0, OUT0#	NA
1		RW	0 = Free running	OUT1, OUT1#	NA
2		RW	0 = Free running	OUT2, OUT2#	NA
3		RW	0 = Free running	OUT3, OUT3#	NA
4		RW	0 = Free running	OUT4, OUT4#	NA
5		RW	0 = Free running	OUT5, OUT5#	NA
6		RW	0 = Free running	OUT6, OUT6#	NA
7		RW	0 = Free running	OUT7, OUT7#	NA

**Data Byte 3: Control Register**

Bit	Descriptions	Type	Power Up Condition	Output(s) Affected	Pin
0	<b>RESERVED</b>	RW			
1		RW			
2		RW			
3		RW			
4		RW			
5		RW			
6		RW			
7		RW			

**PI6C20800S**

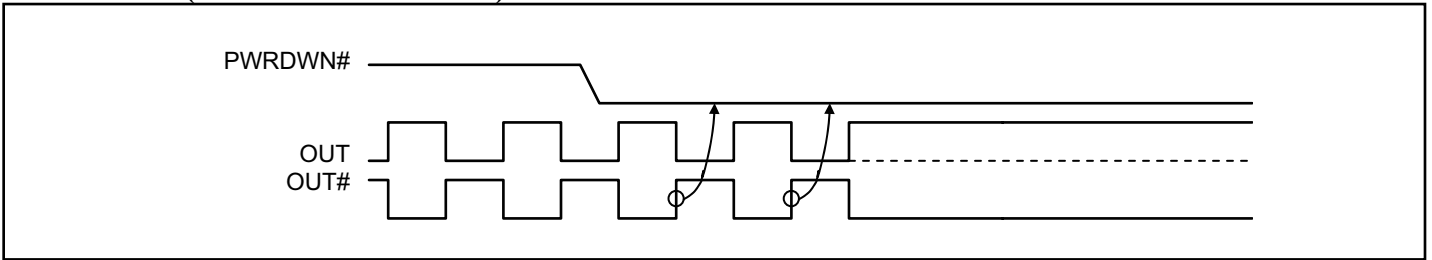
**Data Byte 4: Pericom ID Register**

Bit	Descriptions	Type	Power Up Condition	Output(s) Affected	Pin
0	Pericom ID	R	0	NA	NA
1		R	0	NA	NA
2		R	0	NA	NA
3		R	0	NA	NA
4		R	0	NA	NA
5		R	1	NA	NA
6		R	0	NA	NA
7		R	0	NA	NA

**Functionality**

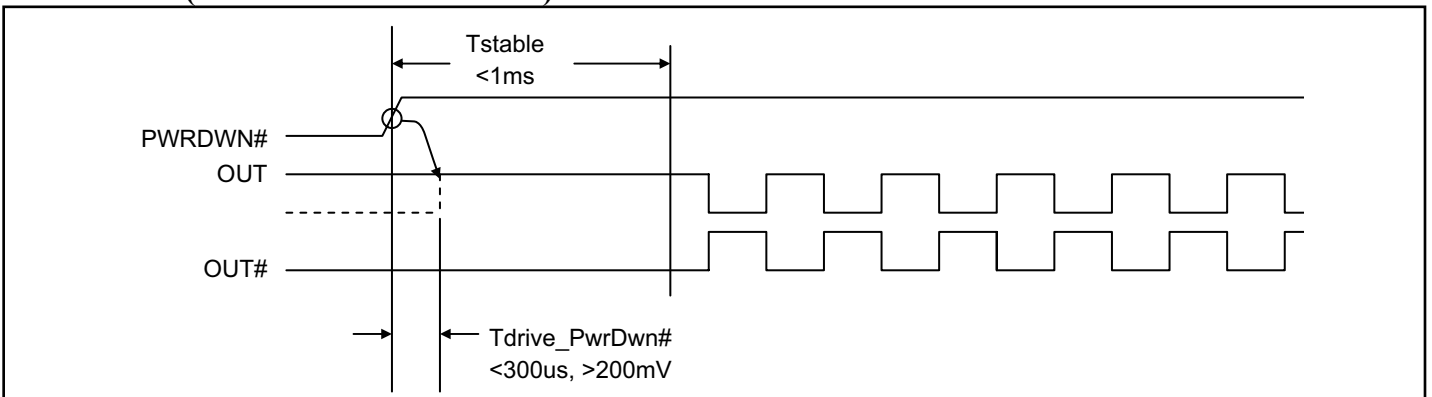
PWRDWN#	OUT	OUT#	SRC_Stop#	OUT	OUT#
1	Normal	Normal	1	Normal	Normal
0	$I_{REF} \times 2$ or Float	LOW	0	$I_{REF} \times 6$ or Float	LOW

**Power Down (PWRDWN# assertion)**



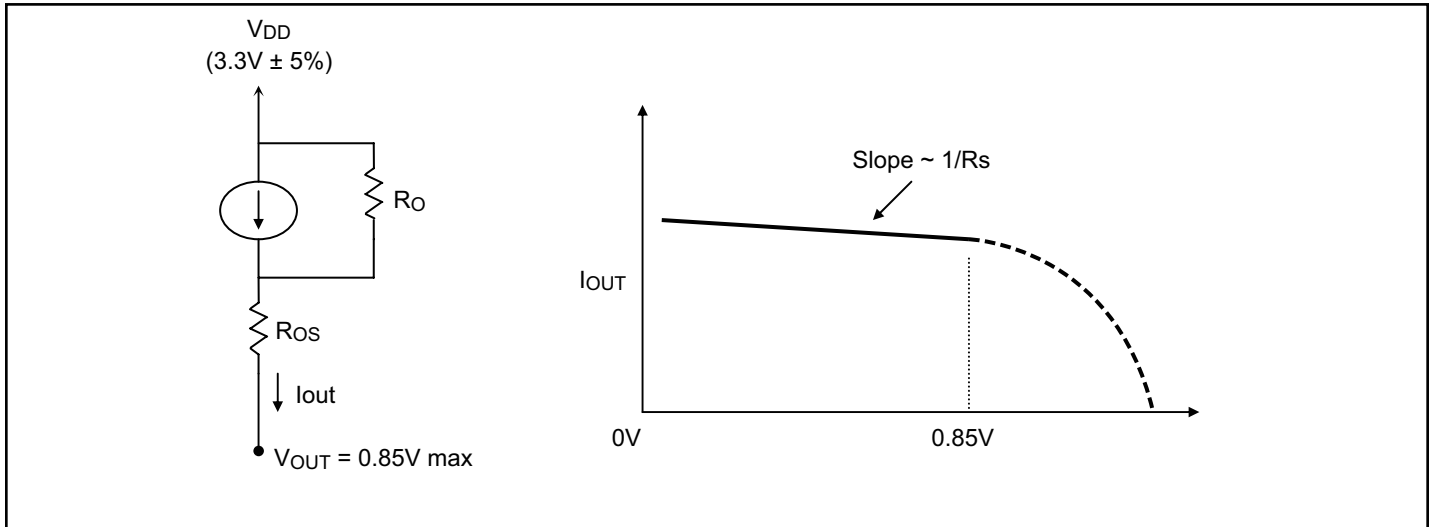
**Figure 1. Power Down Sequence**

**Power Down (PWRDWN# De-assertion)**



**Figure 2. Power Down De-assert Sequence**

**Current-mode Output Buffer Characteristics of OUT[0:7], OUT[0:7]#**



**Figure 3. Simplified Diagram of Current-mode Output Buffer**

**Differential Clock Buffer Characteristics**

Symbol	Minimum	Maximum
$R_O$	3000 $\Omega$	N/A
$R_{OS}$	unspecified	unspecified
$V_{OUT}$	N/A	850mV

**Current Accuracy**

Symbol	Conditions	Configuration	Load	Min.	Max.
$I_{OUT}$	$V_{DD} = 3.30 \pm 5\%$	$R_{REF} = 475\Omega \text{ 1\%}$ $I_{REF} = 2.32mA$	Nominal test load for given configuration	-12% $I_{NOMINAL}$	+12% $I_{NOMINAL}$

**Note:**

- $I_{NOMINAL}$  refers to the expected current based on the configuration of the device.

**Differential Clock Output Current**

Board Target Trace/Term Z	Reference R, $I_{ref} = V_{DD}/(3 \times R_r)$	Output Current	$V_{OH} @ Z$
100 $\Omega$ (100 $\Omega$ differential $\approx$ 15% coupling ratio)	$R_{REF} = 475\Omega \text{ 1\%}$ , $I_{REF} = 2.32mA$	$I_{OH} = 6 \times I_{REF}$	0.7V @ 50



### Absolute Maximum Ratings (Over operating free-air temperature range)

Symbol	Parameters	Min.	Max.	Units
V <sub>DD_A</sub>	3.3V Core Supply Voltage	-0.5	4.6	V
V <sub>DD</sub>	3.3V I/O Supply Voltage	-0.5	4.6	
V <sub>IH</sub>	Input HIGH Voltage		4.6	
V <sub>IL</sub>	Input LOW Voltage	-0.5		
T <sub>s</sub>	Storage Temperature	-65	150	°C
V <sub>ESD</sub>	ESD Protection	2000		V
T <sub>J</sub>	Junction Temperature		125	°C

**Note:**

- Stress beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device.

### DC Electrical Characteristics (V<sub>DD</sub> = 3.3±5%, V<sub>DD\_A</sub> = 3.3±5%)

Symbol	Parameters	Condition	Min.	Max.	Units
V <sub>DD_A</sub>	3.3V Core Supply Voltage		3.135	3.465	V
V <sub>DD</sub>	3.3V I/O Supply Voltage		3.135	3.465	
V <sub>IH</sub>	3.3V Input HIGH Voltage		2.0	V <sub>DD</sub> + 0.3	
V <sub>IL</sub>	3.3V Input LOW Voltage		V <sub>SS</sub> - 0.3	0.8	
I <sub>IK</sub>	Input Leakage Current	0 < V <sub>IN</sub> < V <sub>DD</sub>	-5	+5	µA
V <sub>OH</sub>	3.3V Output HIGH Voltage	I <sub>OH</sub> = -1mA	2.4		V
V <sub>OL</sub>	3.3V Output LOW Voltage	I <sub>OL</sub> = 1mA		0.4	
I <sub>OH</sub>	Output HIGH Current	I <sub>OH</sub> = 6 x I <sub>REF</sub> , I <sub>REF</sub> = 2.32mA	12.2	15.6	mA
C <sub>IN</sub>	Logic Input Pin Capacitance		1.5	5	
C <sub>OUT</sub>	Output Pin Capacitance			6	pF
L <sub>PIN</sub>	Pin Inductance			7	nH
I <sub>DD</sub>	Power Supply Current	V <sub>DD</sub> = 3.465V, F <sub>CPU</sub> = 100MHz		250	mA
I <sub>SS</sub>	Power Down Current	Driven outputs		80	
I <sub>SS</sub>	Power Down Current	Tristate outputs		12	
T <sub>A</sub>	Ambient Temperature	Commercial (PI6C20800S)	0	70	°C
		Industrial (PI6C20800SI)	-40	85	

**AC Switching Characteristics** ( $V_{DD} = 3.3 \pm 5\%$ ,  $V_{DD\_A} = 3.3 \pm 5\%$ )

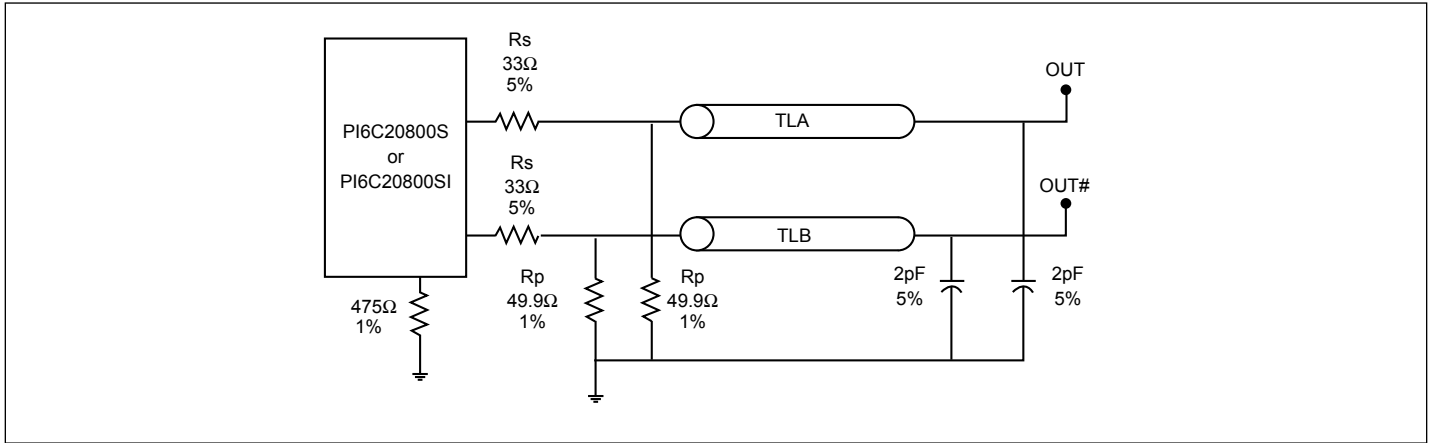
Symbol	Parameters	Min.	Max.	Units	Notes	
$F_{in}$	SRC/SRC# Input Frequency PLL Mode	95	105	MHz	6	
	SRC/SRC# Input Frequency Bypass Mode	95	400	MHz	6	
$T_{rise} / T_{fall}$	Rise and Fall Time (measured between 0.175V to 0.525V)	175	700	ps	2	
$\Delta T_{rise} / \Delta T_{fall}$	Rise and Fall Time Variation		125		2	
$T_{pd}$	Input to Output Propagation Delay	PLL Mode	PI6C20800S	-250	250	ps
			PI6C20800SI	-450	450	
		Bypass Mode	PI6C20800S	-6	6	ns
			PI6C20800SI	-8	8	
$T_{skew}$	Output-to-Output Skew (PI6C20800S)		50	ps	3	
	Output-to-Output Skew (PI6C20800SI)		65		3	
$V_{HIGH}$	Voltage HIGH (Measured at 100MHz @ 3.3V)	600	900	mV	2	
$V_{OVS}$	Max. Voltage		1150			
$V_{UDS}$	Min. Voltage	-300				
$V_{LOW}$	Voltage LOW	-150	+150		2	
$V_{cross}$	Absolute crossing poing voltages	250	550		2	
$\Delta V_{cross}$	Total Variation of $V_{cross}$ over all edges		140		2	
$T_{DC}$	Duty Cycle (Measured at 100 MHz)	45	57	%	3	
$T_{jyc-cyc}$	Jitter, Cycle-to-cycle (PLL Mode, Measurement for differential waveform)		70	ps	4	
	Jitter, Cycle-to-cycle (BYPASS mode as additive jitter)					
$J_{add}$	Additive RMS phase jitter for PCIe 2.0	<0	1	ps	5	

**Notes:**

1. Test configuration is  $R_s = 33.2\Omega$ ,  $R_p = 49.9\Omega$ , and 2pF.
2. Measurement taken from Single Ended waveform.
3. Measurement taken from Differential waveform.
4. Measured using M1 timing analyzer from Amherst.
5. Additive jitter is calculated from input and output RMS phase jitter by using PCIe 2.0 filter. ( $J_{add} = \sqrt{(\text{output jitter})^2 - (\text{input jitter})^2}$ )
6. -0.5% downspread input

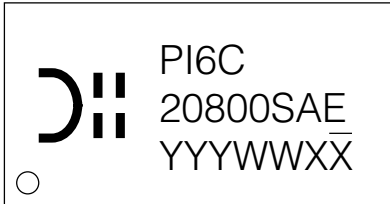
**PI6C20800S**

**Configuration Test Load Board Termination**



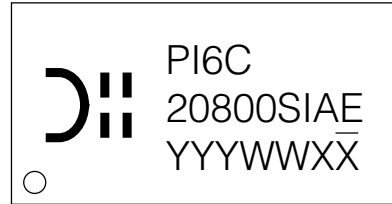
**Part Marking**

A Package



Y: Die Rev  
YY: Year  
WW: Workweek  
1st X: Assembly Code  
2nd X: Fab Code

A Package - Industrial



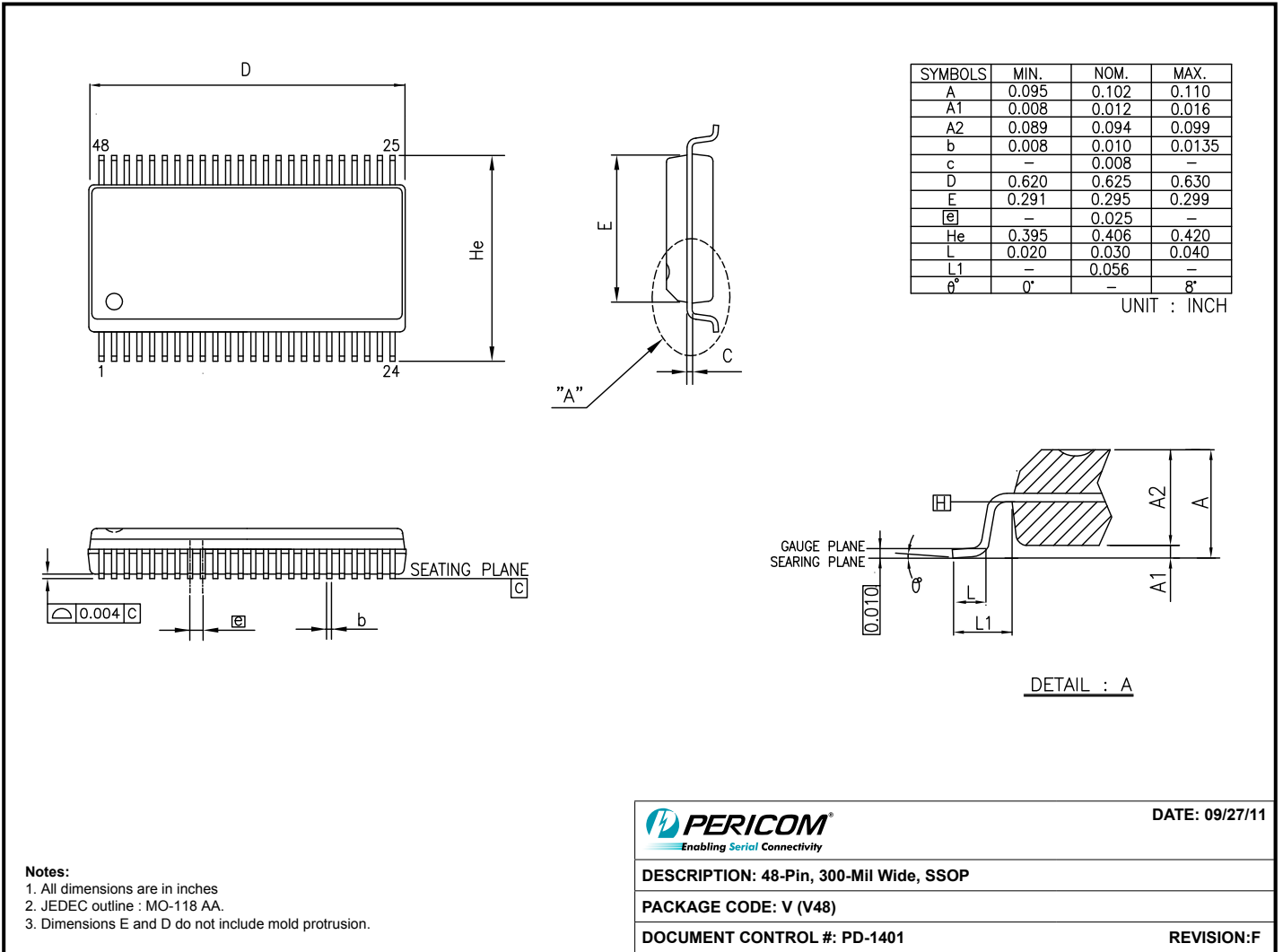
Y: Die Rev  
YY: Year  
WW: Workweek  
1st X: Assembly Code  
2nd X: Fab Code

V Package

Top mark not available at this time. To obtain advance information regarding the top mark, please contact your local sales representative.

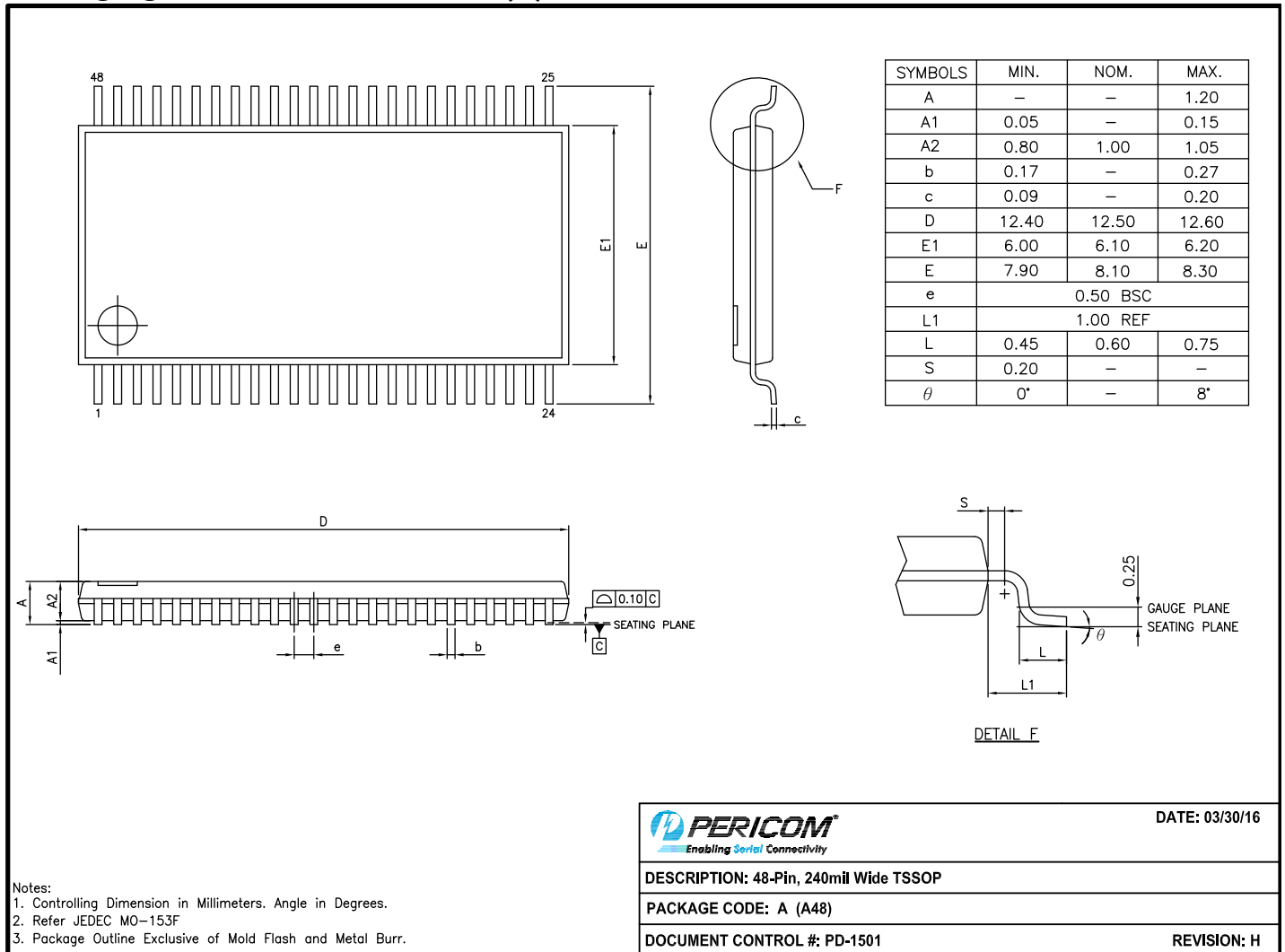
**PI6C20800S**

**Packaging Mechanical: 48-SSOP (V)**



**PI6C20800S**

**Packaging Mechanical: 48-TSSOP (A)**



16-0065

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**Ordering Information**

Ordering Code	Package Code	Package Description
PI6C20800SVEX	V	48-pin, 300-mil wide (SSOP)
PI6C20800SAEX	A	48-pin, 240-mil wide (TSSOP)
PI6C20800SIAEX	A	48-pin, 240-mil wide (TSSOP) (Industrial)

**Notes:**

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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